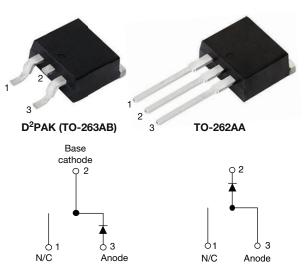
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## VS-ETL1506S-M3, VS-ETL1506-1-M3

Vishay Semiconductors

# Ultrafast Rectifier, 15 A FRED Pt<sup>®</sup>



VS-ETL1506S-M3

VS-ETL1506-1-M3

PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	15 A				
V <sub>R</sub>	600 V				
V <sub>F</sub> at I <sub>F</sub>	0.85 V				
t <sub>rr</sub> (typ.)	60 ns				
T <sub>J</sub> max.	175 °C				
Package	D <sup>2</sup> PAK (TO-263AB), TO-262AA				
Circuit configuration	Single				

#### FEATURES

- State of the art low forward voltage drop
- Ultrafast recovery time
- 175 °C operating junction temperature
- Low leakage current
- Designed and qualified according to  ${\sf JEDEC}^{\circledast}{\sf -}{\sf JESD}$  47
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### DESCRIPTION

State of the art, ultralow  $V_F$ , soft-switching ultrafast rectifiers optimized for Discontinuous (Critical) Mode (DCM) Power Factor Correction (PFC).

The minimized conduction loss, optimized stored charge and low recovery current minimized the switching losses and reduce over dissipation in the switching element and snubbers.

The device is also intended for use as a freewheeling diode in power supplies and other power switching applications.

### APPLICATIONS

AC/DC SMPS 70 W to 400 W

e.g. laptop and printer AC adaptors, desktop PC, TV and monitor, games units, and DVD AC/DC power supplies.

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Repetitive peak reverse voltage	V <sub>RRM</sub>		600	V
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 152 °C	15	^
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>C</sub> = 25 °C	200	A
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C

ELECTRICAL SPECIFICATI	ONS (T <sub>J</sub> =	25 °C unless otherwise specified)				
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	$V_{BR}, V_{R}$	I <sub>R</sub> = 100 μA	600	-	-	
Forward voltage	V	I <sub>F</sub> = 15 A	-	0.99	1.07	V
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 15 A, T <sub>J</sub> = 150 °C	-	0.85	0.91	
Deverae leekege eurrent	1	V <sub>R</sub> = V <sub>R</sub> rated	-	0.01	15	
Reverse leakage current	I <sub>R</sub>	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	6	100	μA
Junction capacitance	CT	V <sub>R</sub> = 600 V	-	12	-	pF
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8.0	-	nH

Revision: 21-Dec-2021

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Document Number: 96333

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DYNAMIC RECOVERY CHAR	ACTERIS	<b>STICS</b> (T <sub>J</sub> = 25 °C	unless otherwise spe	ecified)			
PARAMETER	SYMBOL	TEST C	ONDITIONS	MIN.	TYP.	MAX.	UNITS
		$I_F = 1 \text{ A}, \ dI_F/dt = 100$	0 A/µs, V <sub>R</sub> = 30 V	-	60	110	
Boyoraa raadyony tima	t <sub>rr</sub>	$I_F = 15 \text{ A}, \text{ d}I_F/\text{d}t = 10$	$I_F = 15 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		185	270	20
Reverse recovery time t	۲rr	T <sub>J</sub> = 25 °C		-	210	-	ns
		T <sub>J</sub> = 125 °C	I <sub>F</sub> = 15 A dI <sub>F</sub> /dt = 200 A/μs V <sub>B</sub> = 390 V	-	290	-	
Peak recovery current		T <sub>J</sub> = 25 °C		-	20	-	А
Feak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C		-	26	-	A
	0	T <sub>J</sub> = 25 °C	] ''	-	2.2	-	μC
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	4.0	-	μΟ

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C
Thermal resistance, junction to case	R <sub>thJC</sub>		-	1.3	1.51	°C/W
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Typical socket mount	-	-	70	
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth, and greased	-	0.5	-	
Weight			-	2.0	-	g
weight			-	0.07	-	oz.
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)
Marking davias		Case style D <sup>2</sup> PAK (TO-263AB)		ETL1	506S	
Marking device		Case style TO-262		ETL1	506-1	

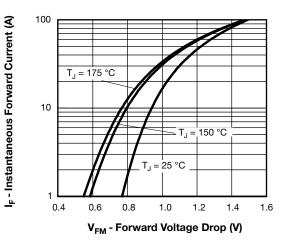


Fig. 1 - Typical Forward Voltage Drop Characteristics

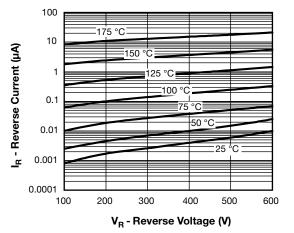


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



## VS-ETL1506S-M3, VS-ETL1506-1-M3

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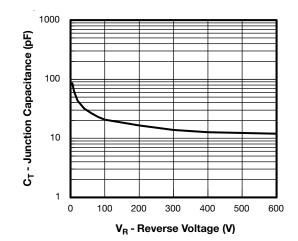


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

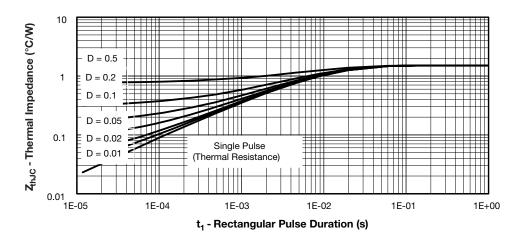
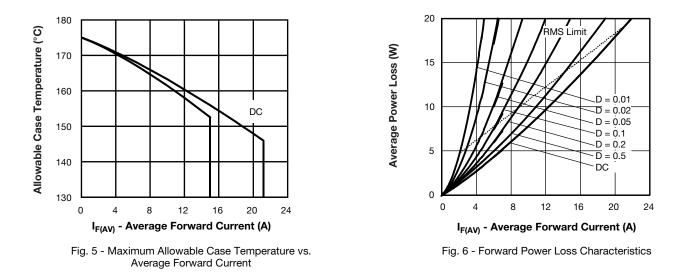


Fig. 4 - Max. Thermal Impedance Z<sub>thJC</sub> Characteristics



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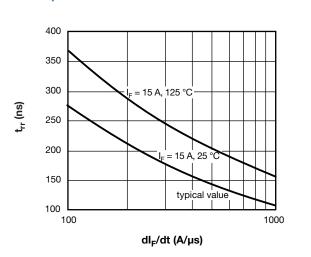
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## VS-ETL1506S-M3, VS-ETL1506-1-M3





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Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

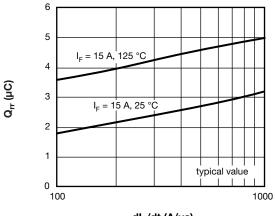




Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

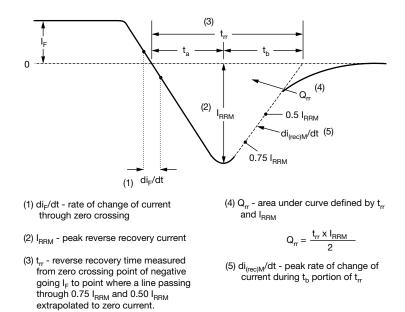


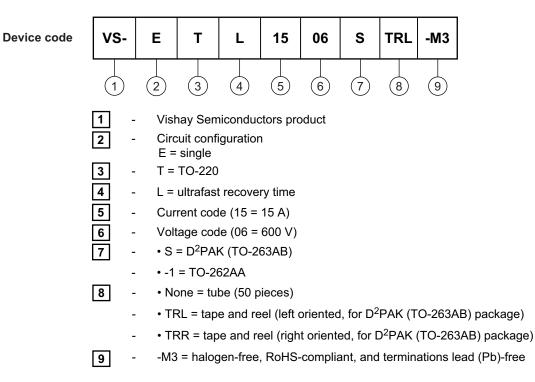
Fig. 9 - Reverse Recovery Waveform and Definitions

## VS-ETL1506S-M3, VS-ETL1506-1-M3



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## **ORDERING INFORMATION TABLE**



ORDERING INFORMATION (Example)				
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION		
VS-ETL1506S-M3	50	Antistatic plastic tubes		
VS-ETL1506STRR-M3	800	13" diameter plastic tape and reel		
VS-ETL1506STRL-M3	800	13" diameter plastic tape and reel		
VS-ETL1506-1-M3	50	Antistatic plastic tubes		

	LINKS TO RELATED D	DCUMENTS
Dimensions	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?96164
Dimensions	TO-262AA	www.vishay.com/doc?96165
Port marking information	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?95444
Part marking information	TO-262AA	www.vishay.com/doc?95443
Packaging information	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?96424

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D<sup>2</sup>PAK

#### **DIMENSIONS** in millimeters and inches



ota	ted	90	°C
<u>S</u>	cale	<u>ə:</u> 8	:1

SYMBOL	MILLIM	ETERS	INC	HES	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
A	4.06	4.83	0.160	0.190		
A1	0.00	0.254	0.000	0.010		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
с	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	

SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STNDUL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25	BSC	0.010	BSC	
L4	4.78	5.28	0.188	0.208	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

(3) Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

(5) Datum A and B to be determined at datum plane H

(6) Controlling dimension: inches

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-263AB

Revision: 13-Jul-17

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Document Number: 96164

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## **Outline Dimensions**



**Vishay Semiconductors** 

**TO-262AA** 

#### **DIMENSIONS** in millimeters and inches





F D1 (3) (3) Section A - A Base (4) Plating b1. b3 metal ≰ c1 (4) -(b, b2)-Section B - B and C - C Scale: None





Diodes 1. - Anode (two die)/open (one die) 2., 4. - Cathode 3. - Anode

Lead assignments

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	BSC	0.100	) BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

 <sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994
<sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the second dimensioner of the second dimensis of the second dimensioner of the second dimensioner of the the outmost extremes of the plastic body (3)

Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only (5)

Controlling dimension: inches

(6) Outline conform to JEDEC® TO-262 except A1 (max.), b (min., max.), b1 (min.), b2 (max.), c (min.), c1(min.), c2 (max.), D (min.), E (max.), L1 (max.), L2 (min., max.)

Revision: 30-Nov-17

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